

Description

The SX10P03SI uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = -30V$ $I_D = 10A$

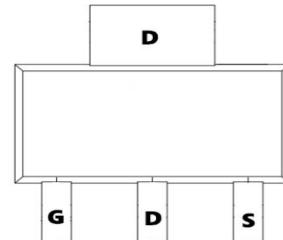
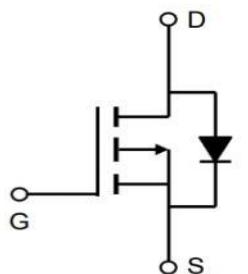
$R_{DS(ON)} < 20m\Omega$ @ $V_{GS}=10V$

Application

Lithium battery protection

Wireless impact

Mobile phone fast charging

**Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)**

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_c=25^\circ C$	Continuous Drain Current, $V_{GS} @ -10V$ 1	-10	A
$I_D@T_c=100^\circ C$	Continuous Drain Current, $V_{GS} @ -10V$ 1	-7.8	A
I_{DM}	Pulsed Drain Current2	-30	A
E_{AS}	Single Pulse Avalanche Energy3	125	mJ
$P_{D@T_c=25^\circ C}$	Total Power Dissipation4	29	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C
$R_{\theta JA}$	Thermal Resistance Junction-Ambient 1	125	°C/W
$R_{\theta JC}$	Thermal Resistance Junction-Case1	3.6	°C/W

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$, $I_D=-250\mu\text{A}$	-30	-33	-	V
IDSS	Zero Gate Voltage Drain Current	$V_{DS}=-30\text{V}$, $V_{GS}=0\text{V}$,	-	-	-1	μA
IGSS	Gate to Body Leakage Current	$V_{DS}=0\text{V}$, $V_{GS}=\pm 20\text{V}$	-	-	± 100	nA
VGS(th)	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=-250\mu\text{A}$	-1.2	-1.5	-2.5	V
RDS(on)	Static Drain-Source on-Resistance note3	$V_{GS}=-10\text{V}$, $I_D=-10\text{A}$	-	16	20	$\text{m}\Omega$
		$V_{GS}=-4.5\text{V}$, $I_D=-5\text{A}$	-	25	30	
Ciss	Input Capacitance	$V_{DS}=-15\text{V}$, $V_{GS}=0\text{V}$, $f=1.0\text{MHz}$	-	1250	-	pF
Coss	Output Capacitance		-	327	-	pF
Crss	Reverse Transfer Capacitance		-	278	-	pF
Qg	Total Gate Charge	$V_{DS}=-15\text{V}$, $I_D=-9.1\text{A}$, $V_{GS}=-10\text{V}$	-	30	-	nC
Qgs	Gate-Source Charge		-	5.3	-	nC
Qgd	Gate-Drain("Miller") Charge		-	7.6	-	nC
td(on)	Turn-on Delay Time		-	14	-	ns
tr	Turn-on Rise Time	$V_{DD}=-15\text{V}$, $I_D=-6\text{A}$, $V_{GS}=-10\text{V}$, $R_{GEN}=2.5\Omega$	-	20	-	ns
td(off)	Turn-off Delay Time		-	95	-	ns
tf	Turn-off Fall Time		-	65	-	ns
IS	Maximum Continuous Drain to Source Diode Forward Current		-	-	-10	A
ISM	Maximum Pulsed Drain to Source Diode Forward Current		-	-	-40	A
VSD	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}$, $I_S=-11\text{A}$	-	-0.8	-1.2	V

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- 3、The power dissipation is limited by 150°C junction temperature
- 4、The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.

Typical Characteristics

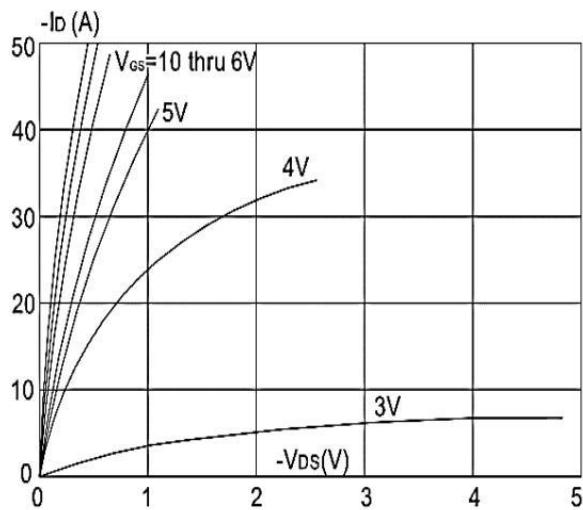


Figure 1: Output Characteristics

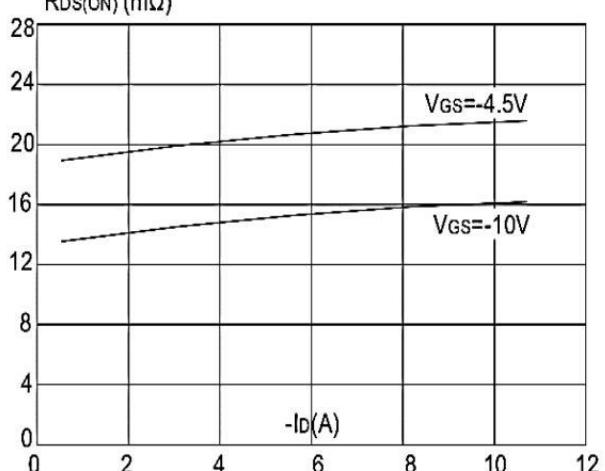


Figure 3: On-resistance vs. Drain Current

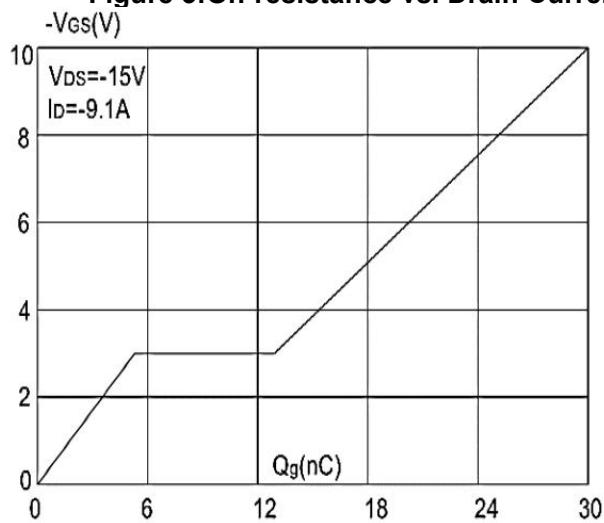


Figure 5: Gate Charge Characteristics

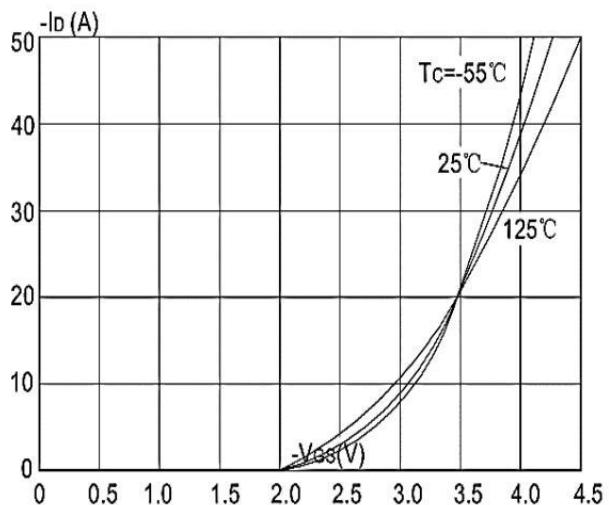


Figure 2: Typical Transfer Characteristics

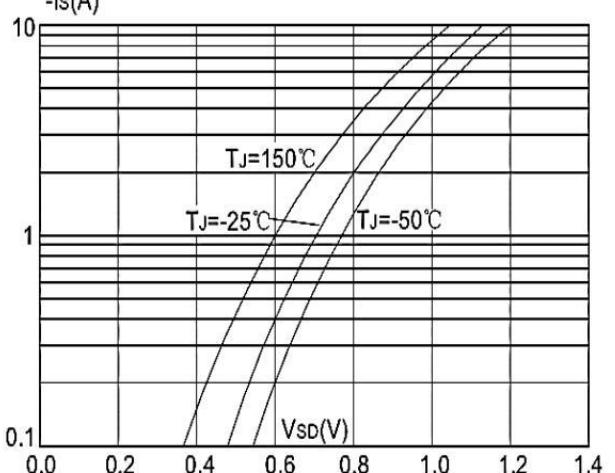


Figure 4: Body Diode Characteristics

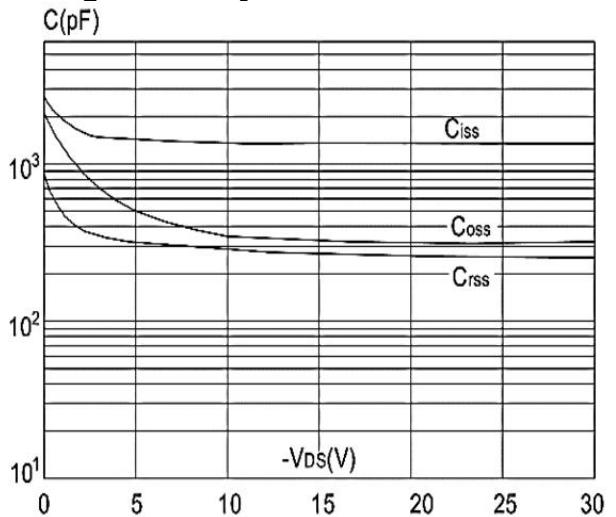


Figure 6: Capacitance Characteristics

Typical Characteristics

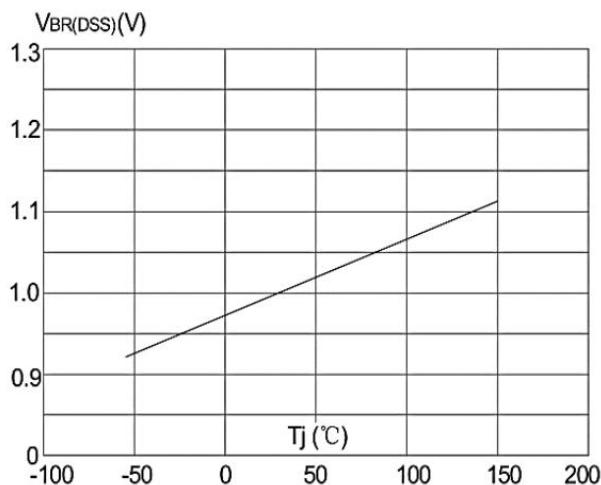


Figure 7: Normalized Breakdown Voltage vs.
Junction Temperature

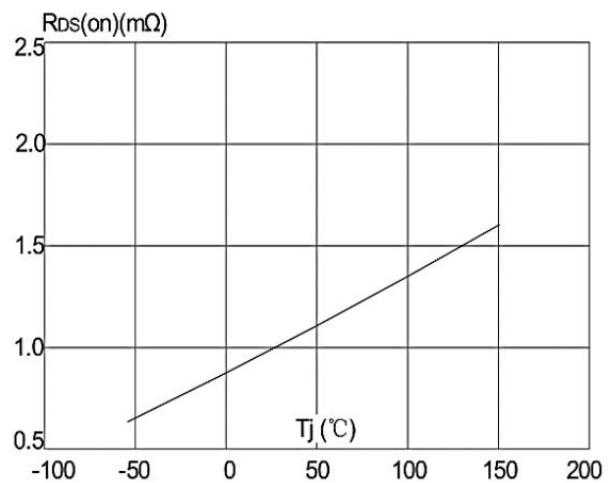


Figure 8: Normalized on Resistance vs.
Junction Temperature

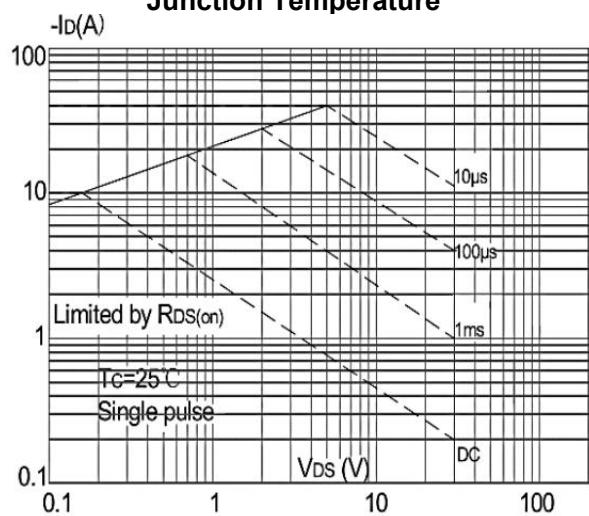


Figure 9: Maximum Safe Operating Area

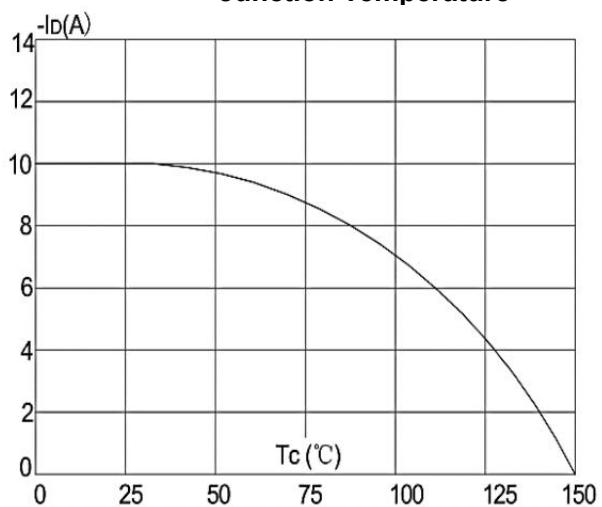


Figure 10: Maximum Continuous Drain Current
vs. Ambient Temperature

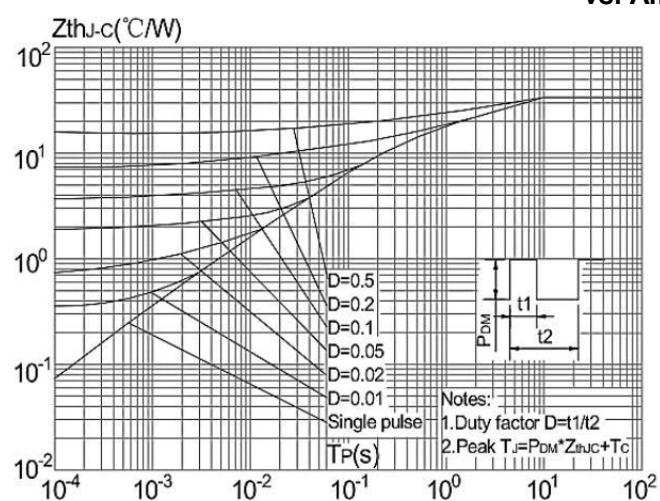
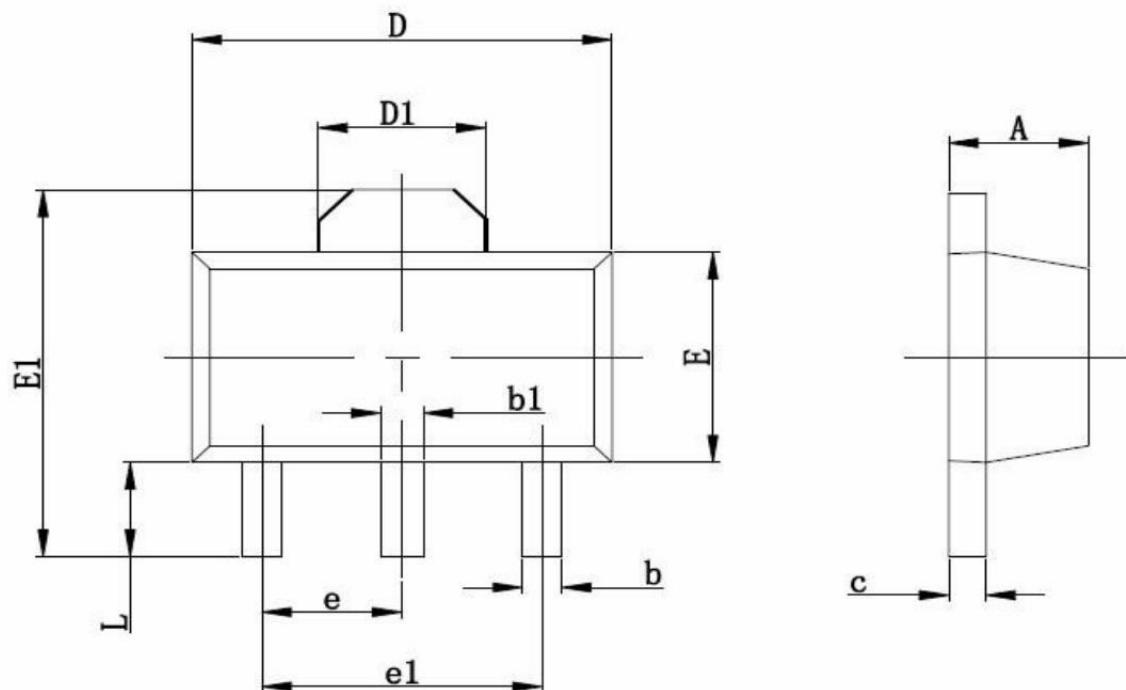


Figure 11: Maximum Effective
Transient Thermal Impedance, Junction-to-Ambient

Package Mechanical Data:SOT89-3L



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.350	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.350	2.550	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060TYP	
e1	3.000 TYP		0.118TYP	
L	0.900	1.100	0.035	0.047

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	SOT89-3L		3000